

# NEC

## NPN SILICON EPITAXIAL TWIN TRANSISTOR

## UPA835TF

### FEATURES

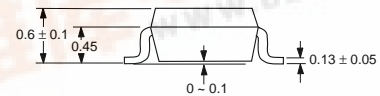
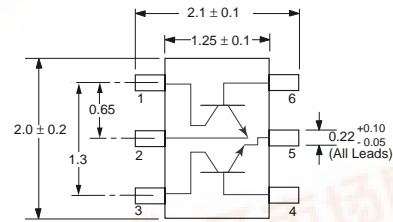
- LOW NOISE:**  
Q1:NF = 1.5 dB TYP at f = 2 GHz, VCE = 3 V, Ic = 3 mA  
Q2:NF = 1.2 dB TYP at f = 1 GHz, VCE = 3 V, Ic = 7 mA
- HIGH GAIN:**  
Q1: |S<sub>21E</sub>|<sup>2</sup> = 8.5 dB TYP at f = 1 GHz, VCE = 3 V, Ic = 10 mA  
Q2: |S<sub>21E</sub>|<sup>2</sup> = 9.0 dB TYP at f = 1 GHz, VCE = 3 V, Ic = 7 mA
- 6-PIN THIN-TYPE SMALL MINI MOLD PACKAGE**
- 2 DIFFERENT BUILT-IN TRANSISTORS (Q1: NE685, Q2: NE856)**

### DESCRIPTION

The UPA835TF has two different built-in transistors for low cost amplifier and oscillator applications in the VHF/UHF band. Low noise figures, high gain, high current capability, and medium output give this device high dynamic range and excellent linearity for two-stage amplifiers. This device is also ideally suited for use in a VCO/buffer amplifier application. The thinner package style allows for higher density designs.

### OUTLINE DIMENSIONS (Units in mm)

Package Outline TS06 (Top View)



#### PIN CONNECTIONS

- Collector (Q1)
- Emitter (Q1)
- Collector (Q2)
- Base (Q2)
- Emitter (Q2)
- Base (Q1)

#### Note:

Pin 1 is the lower left most pin as the package lettering is oriented and read left to right.

### ELECTRICAL CHARACTERISTICS (TA = 25°C)

PART NUMBER PACKAGE OUTLINE				UPA835TF TS06		
	SYMBOLS	PARAMETERS AND CONDITIONS	UNITS	MIN	TYP	MAX
Q1	ICBO	Collector Cutoff Current at VCB = 5 V, IE = 0	μA			0.1
	IEBO	Emitter Cutoff Current at VEB = 1 V, IC = 0	μA			0.1
	hFE	DC Current Gain <sup>1</sup> at VCE = 3 V, IC = 10 mA		75		150
	ft	Gain Bandwidth at VCE = 3 V, IC = 10 mA, f = 2 GHz	GHz		12	
	Cre	Feedback Capacitance <sup>2</sup> at VCB = 3 V, IE = 0, f = 1 MHz	pF		0.4	0.7
	S <sub>21E</sub>   <sup>2</sup>	Insertion Power Gain at VCE = 3 V, IC = 10 mA, f = 2 GHz	dB	7	8.5	
	NF	Noise Figure at VCE = 3 V, IC = 3 mA, f = 2 GHz	dB		1.5	2.5
Q2	ICBO	Collector Cutoff Current at VCB = 10 V, IE = 0	μA			1.0
	IEBO	Emitter Cutoff Current at VEB = 1 V, IC = 0	μA			1.0
	hFE	DC Current Gain <sup>1</sup> at VCE = 3 V, IC = 7 mA		100		145
	ft	Gain Bandwidth at VCE = 3 V, IC = 7 mA, f = 1 GHz	GHz	3.0	4.5	
	Cre	Feedback Capacitance <sup>2</sup> at VCB = 3 V, IE = 0, f = 1 MHz	pF		0.7	1.5
	S <sub>21E</sub>   <sup>2</sup>	Insertion Power Gain at VCE = 3 V, IC = 7 mA, f = 1 GHz	dB	7	9	
	NF	Noise Figure at VCE = 3 V, IC = 7 mA, f = 1 GHz	dB		1.2	2.5

Notes: 1. Pulsed measurement, pulse width ≤ 350 μs, duty cycle ≤ 2 %.

2. Collector to base capacitance when measured with capacitance meter (automatic balanced bridge method), with emitter connected to guard pin of capacitances meter.

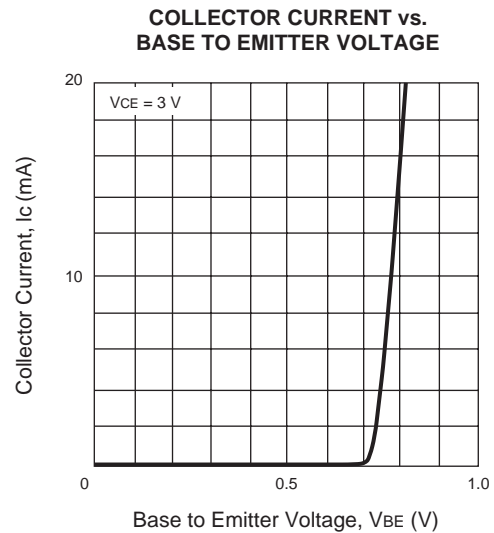
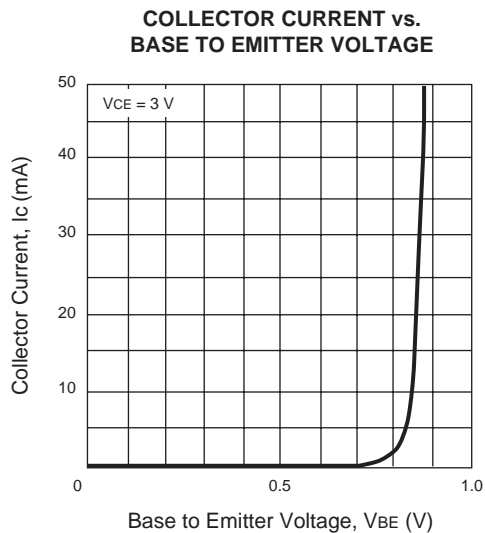
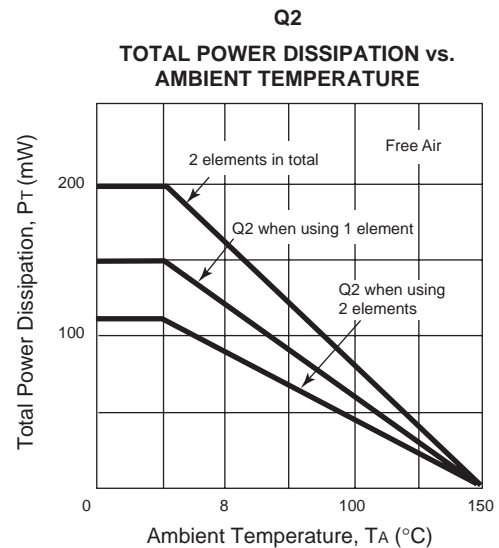
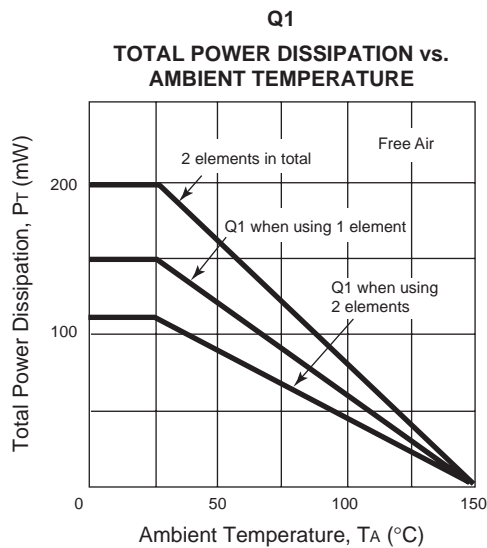
# UPA835TF

## ABSOLUTE MAXIMUM RATINGS<sup>1</sup> (T<sub>A</sub> = 25°C)

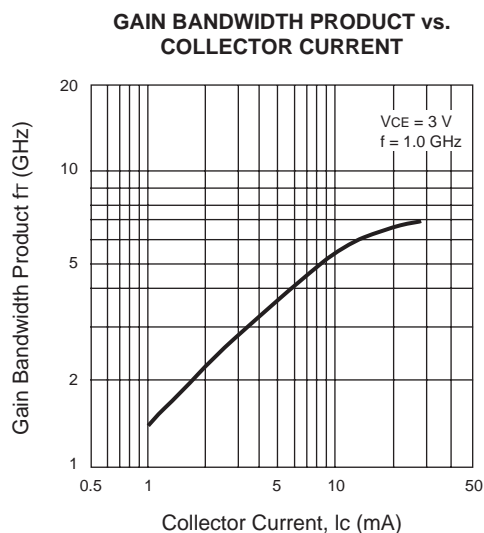
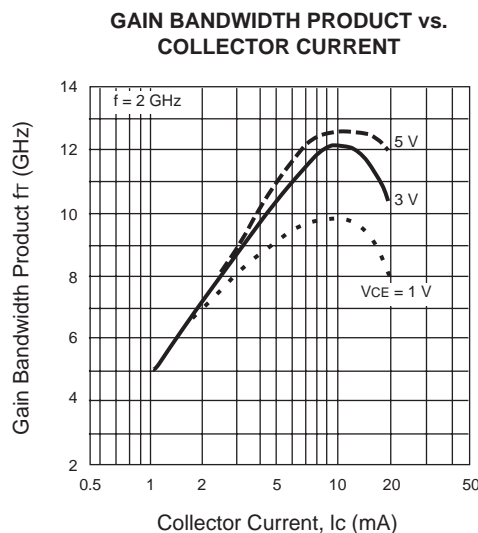
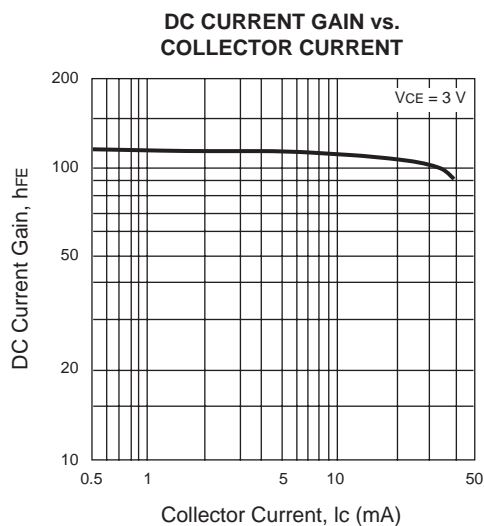
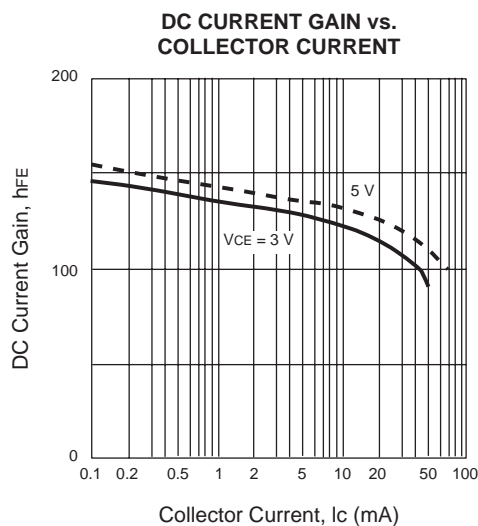
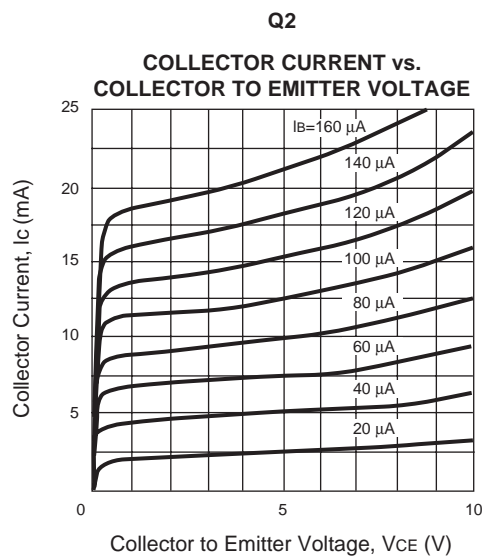
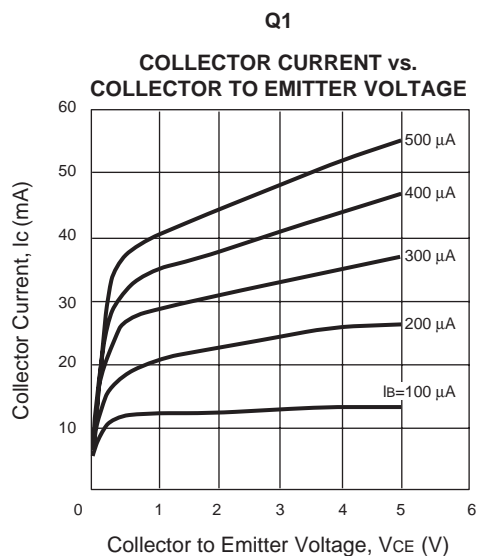
SYMBOLS	PARAMETERS	UNITS	RATINGS	
			Q1	Q2
V <sub>CB0</sub>	Collector to Base Voltage	V	9	20
V <sub>CE0</sub>	Collector to Emitter Voltage	V	6	12
V <sub>EB0</sub>	Emitter to Base Voltage	V	2	3
I <sub>c</sub>	Collector Current	mA	30	100
P <sub>T</sub>	Total Power Dissipation	mW	150	150
			200 <sup>2</sup>	
T <sub>J</sub>	Junction Temperature	°C	150	150
T <sub>STG</sub>	Storage Temperature	°C	-65 to +150	

- Note: 1. Operation in excess of any one of these parameters may result in permanent damage.  
 2. When operating both devices, the power dissipation for either device should not exceed 110 mW.

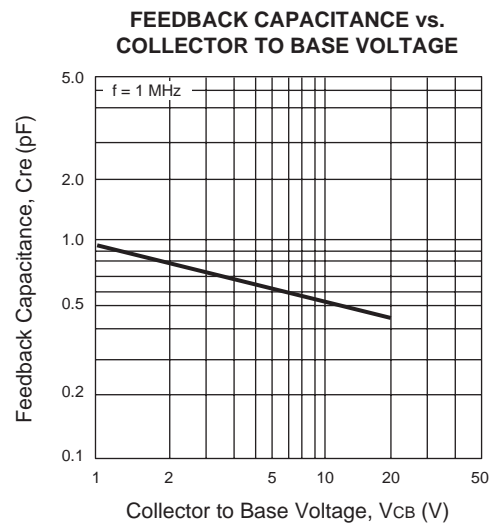
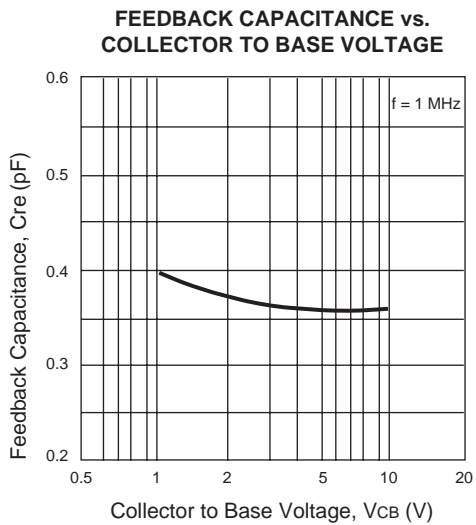
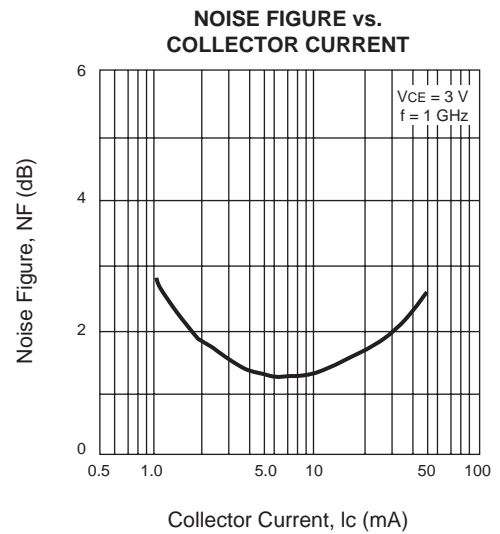
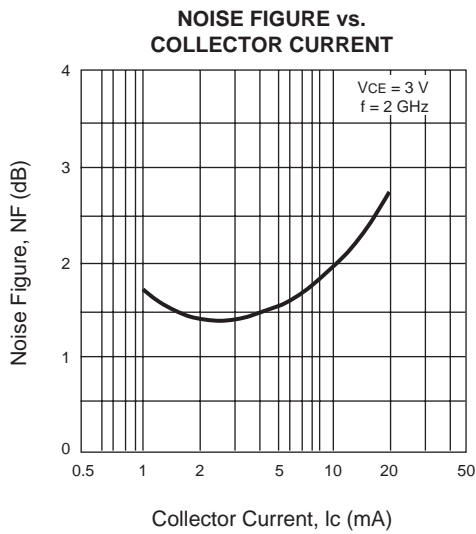
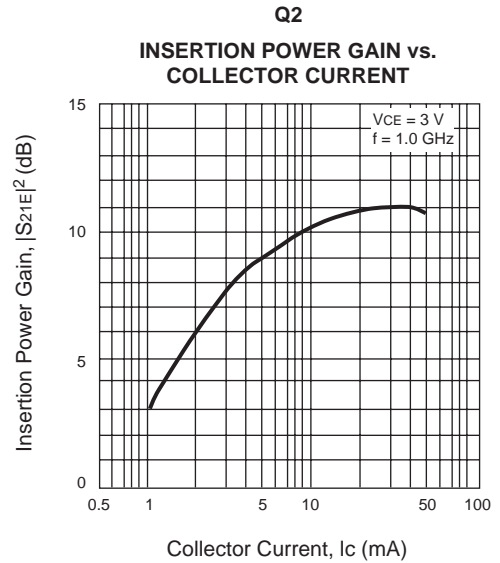
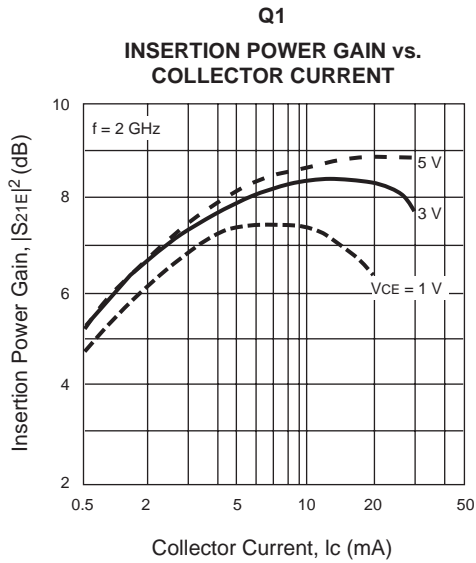
## TYPICAL PERFORMANCE CURVES (T<sub>A</sub> = 25°C)



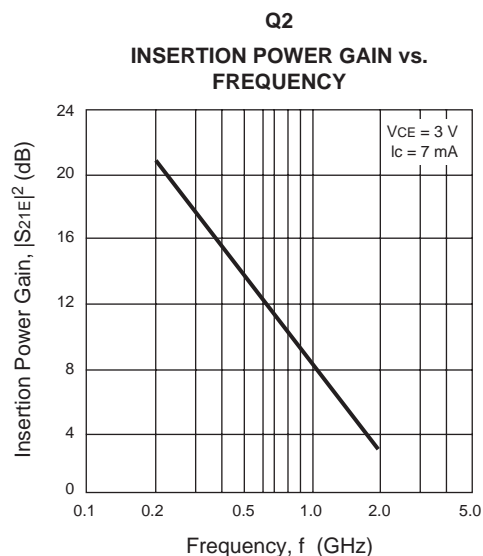
TYPICAL PERFORMANCE CURVES (TA = 25°C)



TYPICAL PERFORMANCE CURVES (TA = 25°C)



## TYPICAL PERFORMANCE CURVES (T<sub>A</sub> = 25°C)



## TYPICAL SCATTERING PARAMETERS

### Q1

VCE = 3 V, Ic = 1 mA, Z<sub>0</sub> = 50 Ω

FREQUENCY (GHz)	S <sub>11</sub>		S <sub>21</sub>		S <sub>12</sub>		S <sub>22</sub>	
	MAG	ANG	MAG	ANG	MAG	ANG	MAG	ANG
0.10	0.98	-5.93	2.38	172.32	0.02	85.76	1.00	-3.86
0.20	0.97	-11.90	2.36	165.08	0.04	81.15	0.99	-7.44
0.30	0.95	-18.17	2.39	158.35	0.06	76.27	0.97	-11.14
0.40	0.93	-24.00	2.35	151.83	0.07	72.22	0.96	-14.73
0.50	0.90	-30.10	2.35	145.70	0.09	68.30	0.94	-18.02
0.60	0.87	-36.17	2.33	140.22	0.10	64.18	0.92	-21.42
0.70	0.84	-42.49	2.30	134.45	0.12	60.68	0.89	-24.18
0.80	0.80	-48.69	2.29	129.32	0.13	56.90	0.87	-27.47
0.90	0.76	-55.28	2.29	123.53	0.14	53.94	0.84	-29.94
1.00	0.73	-61.26	2.24	118.31	0.15	51.07	0.81	-32.50
1.20	0.64	-74.79	2.19	108.30	0.16	45.85	0.76	-36.89
1.50	0.51	-96.77	2.10	93.80	0.18	39.24	0.69	-42.90
1.70	0.43	-112.09	2.00	84.74	0.19	36.24	0.65	-46.39
2.00	0.35	-138.38	1.84	72.75	0.19	32.40	0.60	-51.51
2.50	0.31	175.03	1.62	54.64	0.20	29.55	0.53	-59.91
3.00	0.35	140.64	1.41	40.02	0.21	28.96	0.47	-69.74

### Q2

VCE = 3 V, Ic = 1 mA, Z<sub>0</sub> = 50 Ω

FREQUENCY (GHz)	S <sub>11</sub>		S <sub>21</sub>		S <sub>12</sub>		S <sub>22</sub>	
	MAG	ANG	MAG	ANG	MAG	ANG	MAG	ANG
0.10	0.97	-20.79	2.52	162.21	0.04	76.22	0.98	-8.81
0.20	0.93	-40.50	2.43	147.42	0.08	63.75	0.93	-16.39
0.30	0.89	-59.73	2.35	134.45	0.11	53.38	0.87	-22.34
0.40	0.84	-76.87	2.20	123.37	0.13	44.64	0.81	-27.24
0.50	0.80	-93.28	2.11	113.14	0.14	38.01	0.76	-30.90
0.60	0.76	-107.72	1.99	104.15	0.15	32.06	0.71	-34.29
0.70	0.74	-120.25	1.85	96.02	0.16	27.52	0.68	-36.96
0.80	0.71	-131.32	1.74	88.78	0.15	24.29	0.65	-39.46
0.90	0.69	-141.35	1.64	82.34	0.15	21.95	0.62	-41.97
1.00	0.68	-150.05	1.53	76.48	0.15	20.46	0.60	-44.52
1.20	0.67	-165.04	1.36	66.07	0.14	19.44	0.57	-50.06
1.50	0.67	176.90	1.17	52.95	0.13	24.64	0.53	-59.83
1.70	0.68	166.97	1.06	45.23	0.13	32.01	0.51	-68.26
2.00	0.69	154.69	0.94	35.40	0.14	44.56	0.48	-82.95
2.50	0.72	137.73	0.79	21.71	0.21	55.71	0.45	-114.70
3.00	0.75	124.46	0.68	11.96	0.30	51.65	0.46	-152.23

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## TYPICAL SCATTERING PARAMETERS

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### Q1

VCE = 3 V, Ic = 3 mA, Zo = 50 Ω

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FREQUENCY (GHz)	S11		S21		S12		S22	
	MAG	ANG	MAG	ANG	MAG	ANG	MAG	ANG
0.10	0.94	-9.29	6.55	168.08	0.02	84.10	0.98	-6.91
0.20	0.90	-18.39	6.32	157.85	0.04	76.93	0.95	-13.21
0.30	0.85	-27.47	6.21	148.76	0.05	71.79	0.91	-18.80
0.40	0.80	-36.15	5.98	140.53	0.06	66.81	0.86	-23.80
0.50	0.74	-44.62	5.77	133.00	0.07	63.60	0.81	-27.41
0.60	0.67	-52.69	5.51	126.23	0.08	60.13	0.76	-31.19
0.70	0.60	-60.71	5.28	119.27	0.09	58.07	0.72	-33.67
0.80	0.54	-68.45	5.03	113.12	0.10	55.93	0.68	-36.31
0.90	0.47	-75.60	4.76	107.23	0.11	54.62	0.64	-38.10
1.00	0.42	-82.57	4.50	101.99	0.11	53.45	0.61	-39.74
1.20	0.32	-96.78	4.02	92.52	0.13	51.59	0.56	-42.63
1.50	0.21	-122.39	3.42	80.83	0.15	49.61	0.50	-46.74
1.70	0.17	-143.90	3.10	74.15	0.16	48.63	0.46	-49.50
2.00	0.16	179.12	2.70	64.83	0.18	46.70	0.42	-54.02
2.50	0.22	136.13	2.24	51.62	0.21	43.76	0.36	-63.34
3.00	0.29	115.80	1.89	39.81	0.23	40.27	0.31	-75.36

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### Q2

VCE = 3 V, Ic = 3 mA, Zo = 50 Ω

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FREQUENCY (GHz)	S11		S21		S12		S22	
	MAG	ANG	MAG	ANG	MAG	ANG	MAG	ANG
0.10	0.90	-29.30	6.71	155.29	0.04	71.05	0.93	-16.80
0.20	0.82	-56.11	6.09	137.78	0.07	56.98	0.81	-28.76
0.30	0.73	-80.85	5.56	123.40	0.09	48.29	0.68	-35.65
0.40	0.67	-101.56	4.95	111.97	0.10	42.87	0.59	-40.13
0.50	0.62	-118.49	4.38	102.51	0.11	39.94	0.52	-42.64
0.60	0.59	-131.80	3.86	94.93	0.11	38.27	0.47	-44.51
0.70	0.57	-142.87	3.44	88.40	0.11	37.56	0.43	-45.87
0.80	0.56	-152.14	3.11	82.68	0.12	37.77	0.40	-47.30
0.90	0.55	-159.99	2.82	77.69	0.12	38.47	0.38	-48.65
1.00	0.54	-168.88	2.59	73.06	0.13	39.41	0.36	-50.22
1.20	0.55	-178.59	2.21	64.68	0.13	41.56	0.32	-54.00
1.50	0.56	167.41	1.84	53.63	0.15	45.41	0.28	-62.05
1.70	0.57	159.71	1.66	46.97	0.17	47.04	0.25	-70.04
2.00	0.60	149.93	1.45	37.59	0.19	48.39	0.22	-85.71
2.50	0.64	136.23	1.20	23.63	0.25	47.57	0.19	-125.28
3.00	0.68	125.06	1.02	11.49	0.31	42.77	0.23	-169.77

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## TYPICAL SCATTERING PARAMETERS

### Q1

VCE = 3 V, IC = 5 mA, Z0 = 50 Ω

FREQUENCY (GHz)	S11		S21		S12		S22	
	MAG	ANG	MAG	ANG	MAG	ANG	MAG	ANG
0.10	0.90	-12.12	10.05	165.07	0.02	82.08	0.97	-9.12
0.20	0.84	-23.51	9.49	152.86	0.03	74.99	0.92	-17.06
0.30	0.77	-34.84	9.08	142.06	0.05	69.42	0.85	-23.23
0.40	0.69	-45.03	8.52	132.57	0.06	65.57	0.78	-28.22
0.50	0.60	-54.58	7.94	123.96	0.07	63.02	0.72	-31.57
0.60	0.52	-62.89	7.32	116.79	0.08	60.80	0.66	-34.45
0.70	0.44	-70.48	6.74	109.99	0.08	59.78	0.62	-36.34
0.80	0.38	-77.63	6.21	104.22	0.09	58.73	0.58	-38.08
0.90	0.32	-84.12	5.71	99.08	0.10	57.98	0.55	-39.38
1.00	0.28	-90.92	5.28	94.41	0.11	57.45	0.53	-40.58
1.20	0.20	-105.44	4.56	86.53	0.12	56.41	0.48	-42.73
1.50	0.13	-137.90	3.78	76.56	0.14	54.85	0.43	-46.37
1.70	0.11	-167.88	3.39	70.79	0.15	53.69	0.40	-49.23
2.00	0.13	152.80	2.93	62.58	0.18	51.42	0.37	-54.00
2.50	0.21	121.76	2.41	50.64	0.21	47.56	0.31	-64.32
3.00	0.28	107.74	2.03	39.80	0.24	42.91	0.26	-78.22

### Q2

VCE = 3 V, IC = 5 mA, Z0 = 50 Ω

FREQUENCY (GHz)	S11		S21		S12		S22	
	MAG	ANG	MAG	ANG	MAG	ANG	MAG	ANG
0.10	0.83	-36.95	10.41	149.93	0.04	67.41	0.87	-23.15
0.20	0.72	-69.61	9.00	130.38	0.06	54.36	0.70	-36.92
0.30	0.62	-97.36	7.70	115.33	0.07	48.48	0.56	-43.33
0.40	0.56	-117.96	6.47	104.59	0.08	46.08	0.46	-46.73
0.50	0.53	-133.20	5.47	96.45	0.09	45.55	0.40	-48.28
0.60	0.51	-145.02	4.72	89.97	0.10	45.75	0.35	-49.37
0.70	0.50	-154.27	4.13	84.56	0.10	46.29	0.32	-50.23
0.80	0.49	-162.17	3.68	79.59	0.11	47.21	0.29	-50.94
0.90	0.49	-168.79	3.31	75.30	0.12	48.13	0.27	-51.90
1.00	0.49	-174.60	3.02	71.24	0.13	48.87	0.25	-53.05
1.20	0.50	175.37	2.56	63.72	0.14	49.97	0.22	-56.22
1.50	0.52	163.26	2.11	53.63	0.17	50.87	0.18	-64.21
1.70	0.53	156.57	1.90	47.43	0.19	50.65	0.15	-73.44
2.00	0.56	147.71	1.65	38.70	0.22	49.28	0.11	-94.06
2.50	0.61	135.31	1.36	25.02	0.27	45.44	0.11	-153.25
3.00	0.66	124.98	1.16	13.38	0.32	39.42	0.18	-163.89

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## TYPICAL SCATTERING PARAMETERS

### Q1

VCE = 3 V, Ic = 10 mA, Z0 = 50 Ω

FREQUENCY (GHz)	S11		S21		S12		S22	
	MAG	ANG	MAG	ANG	MAG	ANG	MAG	ANG
0.10	0.82	-17.52	16.52	159.99	0.02	80.28	0.94	-12.68
0.20	0.72	-33.22	14.93	144.21	0.03	72.82	0.85	-22.43
0.30	0.60	-46.83	13.32	131.03	0.04	68.07	0.75	-28.43
0.40	0.49	-57.62	11.65	120.45	0.05	65.62	0.67	-32.14
0.50	0.40	-65.90	10.15	112.22	0.06	65.03	0.60	-34.25
0.60	0.33	-72.93	8.90	105.92	0.07	63.86	0.56	-35.78
0.70	0.27	-79.33	7.89	100.37	0.08	63.74	0.52	-36.80
0.80	0.22	-85.38	7.07	95.73	0.08	63.50	0.49	-37.69
0.90	0.18	-91.73	6.39	91.61	0.09	63.16	0.46	-38.46
1.00	0.15	-98.81	5.83	87.88	0.10	62.77	0.45	-39.30
1.20	0.10	-118.22	4.95	81.32	0.11	61.85	0.41	-41.01
1.50	0.07	-176.19	4.05	72.83	0.14	59.79	0.38	-44.69
1.70	0.08	149.79	3.61	67.81	0.15	58.31	0.35	-47.69
2.00	0.13	125.94	3.12	60.46	0.18	55.55	0.32	-53.15
2.50	0.21	109.57	2.54	49.58	0.22	50.37	0.27	-65.07
3.00	0.29	100.79	2.14	39.46	0.25	45.03	0.21	-81.46

### Q2

VCE = 3 V, Ic = 7 mA, Z0 = 50 Ω

FREQUENCY (GHz)	S11		S21		S12		S22	
	MAG	ANG	MAG	ANG	MAG	ANG	MAG	ANG
0.10	0.78	-43.98	13.56	145.65	0.04	65.30	0.83	-28.08
0.20	0.64	-81.06	11.15	124.63	0.05	53.73	0.62	-42.31
0.30	0.55	-109.37	9.00	109.90	0.07	50.12	0.47	-48.09
0.40	0.50	-128.61	7.29	100.27	0.07	49.49	0.39	-50.66
0.50	0.48	-142.36	6.05	93.07	0.08	50.25	0.33	-51.72
0.60	0.47	-152.78	5.16	87.38	0.09	50.94	0.29	-52.25
0.70	0.46	-161.04	4.49	82.41	0.10	51.76	0.26	-52.80
0.80	0.46	-168.03	3.98	77.92	0.11	52.62	0.23	-53.35
0.90	0.46	-173.82	3.57	74.02	0.12	53.24	0.21	-54.00
1.00	0.46	-179.09	3.24	70.24	0.13	53.84	0.19	-55.03
1.20	0.47	171.98	2.75	63.22	0.15	53.97	0.15	-58.07
1.50	0.50	160.99	2.25	53.72	0.18	53.24	0.18	-66.67
1.70	0.51	154.69	2.02	47.63	0.20	52.05	0.20	-78.75
2.00	0.54	146.49	1.75	39.20	0.23	49.60	0.23	-110.79
2.50	0.59	134.74	1.44	26.11	0.28	44.37	0.28	174.41
3.00	0.64	124.73	1.23	14.52	0.33	38.05	0.33	146.24

## BUILT-IN TRANSISTORS

	Q1	Q2
3-pin small mini mold part No.	NE68530	NE85630

## ORDERING INFORMATION

PART NUMBER	QUANTITY	PACKAGING
UPA835TF-T1	3000	Tape & Reel

The UPA832TF features the Q1 and Q2 in inverted positions.



**BJT NONLINEAR MODEL PARAMETERS(1)**

Parameters	Q1	Q2	Parameters	Q1	Q2
IS	7e-16	6e-16	MJC	0.34	0.55
BF	109	120	XCJC	0	0.3
NF	1	0.98	CJS	0	0
VAF	15	10	VJS	0.75	0.75
IKF	0.19	0.08	MJS	0	0
ISE	7.9e-13	32e-16	FC	0.5	0.5
NE	2.19	1.93	TF	2.5e-12	12e-12
BR	1	12	XTF	5.2	6
NR	1.08	0.991	VTF	4.58	10
VAR	12.4	3.9	ITF	0.01	0.2
IKR	Infinity	0.17	PTF	0	0
ISC	0	0	TR	1e-9	1e-9
NC	2	2	EG	1.11	1.11
RE	1.3	0.38	XTB	0	0
RB	10	4.16	XTI	3	3
RBM	8.34	3.6	KF	0	0
IRB	0.009	1.96e-4	AF	1	1
RC	10	2			
CJE	0.4e-12	2.8e-12			
VJE	0.81	1.3			
MJE	0.5	0.5			
CJC	0.18e-12	1.1e-12			
VJC	0.75	0.7			

(1) Gummel-Poon Model

**UNITS**

Parameter	Units
time	seconds
capacitance	farads
inductance	henries
resistance	ohms
voltage	volts
current	amps

**MODEL RANGE**

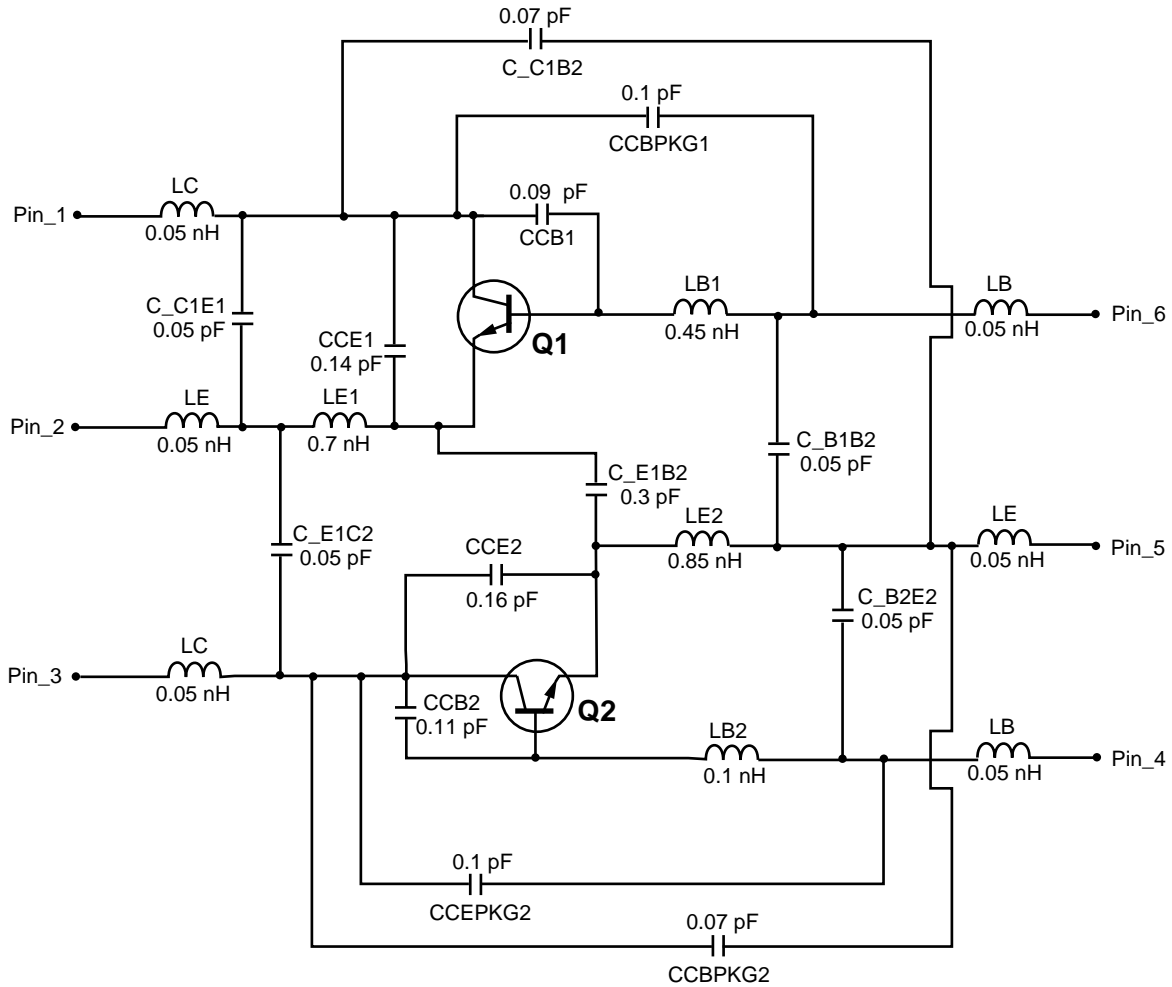
Frequency: 0.1 to 3.0 GHz  
Bias:  $V_{CE} = 0.5 \text{ V to } 5 \text{ V}$ ,  $I_c = 1 \text{ mA to } 10 \text{ mA}$   
Date: 11/98

**Note:**

This nonlinear model utilized the latest data available. See our Design Parameter Library at [www.cel.com](http://www.cel.com) for this data.

# UPA835TF

## SCHEMATIC



### MODEL RANGE

Frequency: 0.1 to 3.0 GHz  
 Bias:  $V_{CE} = 0.5 \text{ V to } 5 \text{ V}$ ,  $I_c = 1 \text{ mA to } 10 \text{ mA}$   
 Date: 11/98

## BUILT-IN TRANSISTORS

	Q1	Q2
3-pin small mini mold part No.	NE68530	NE85630

## ORDERING INFORMATION

PART NUMBER	QUANTITY	PACKAGING
UPA835TF-T1	3000	Tape & Reel

The UPA832TF features the Q1 and Q2 in inverted positions.

EXCLUSIVE NORTH AMERICAN AGENT FOR **NEC** RF, MICROWAVE & OPTOELECTRONIC SEMICONDUCTORS

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